

### INCHANGE SEMICONDUCTOR

## isc N-Channel MOSFET Transistor

### 2SK3176

#### FEATURES

- Drain Current : I\_D= 30A@ T\_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage
  : V<sub>DSS</sub>= 200V(Min)
- Static Drain-Source On-Resistance
- : R<sub>DS(on)</sub> = 52m Ω (Max) @VGS= 10V
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRIPTION

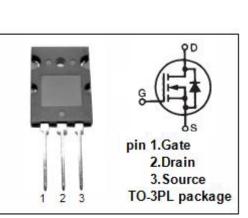
 motor drive, DC-DC converter, power switch and solenoid drive.

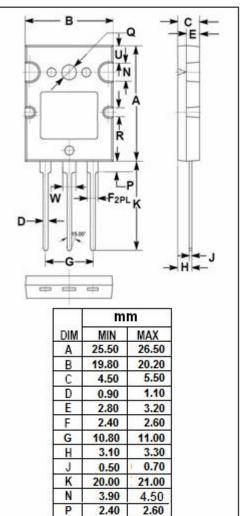
SYMBOL	PARAMETER VALUE		UNIT		
V <sub>DSS</sub>	Drain-Source Voltage	200	V		
V <sub>GS</sub>	Gate-Source Voltage-Continuous ±20		V		
ID	Drain Current-Continuous 30		A		
I <sub>DM</sub>	Drain Current-Single Pluse 120		A		
P <sub>D</sub>	Total Dissipation @Tc=25℃	150	W		
TJ	Max. Operating Junction Temperature	-55~150	°C		
T <sub>stg</sub>	Storage Temperature	-55~150	°C		

# ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

#### **THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.833	°C/W





3.10

1.90

3.90

3.50

2.60

3.25

isc website: <u>www.iscsemi.com</u>

<sup>1</sup> *isc & iscsemi* is registered trademark

Q

R

U

W



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#### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 10mA	200		V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> = 1mA	1.5	3.5	V
R <sub>DS</sub> (on)	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 15A		52	mΩ
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±16V;V <sub>DS</sub> =0		±10	uA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 200V; V <sub>GS</sub> = 0		0.1	mA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 30A; V <sub>GS</sub> = 0		2	V

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